

# **HL6738MG**

## Visible High Power Laser Diode

ODE-208-047 (Z) Rev.0 Sept. 25, 2006

### **Description**

The HL6738MG is a  $0.68~\mu m$  band AlGaInP laser diode (LD) with a multi-quantum well (MQW) structure. It is suitable as a light source for various other types of optical equipment.

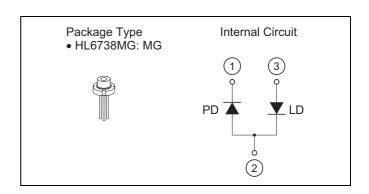
#### **Features**

High output power : 35 mW (CW)
 Visible light output : λp = 690 nm Typ

• Small package : \$\phi\$ 5.6 mm

• Low astigmatism :  $6 \mu m \text{ Typ } (P_O = 5 \text{ mW})$ 

• Single longitudinal mode



## **Absolute Maximum Ratings**

 $(T_C = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Optical output power	Po	35	mW
Pulse optical output power	P <sub>O(pulse)</sub>	50 *	mW
Laser diode reverse voltage	$V_{R(LD)}$	2	V
Photo diode reverse voltage	V <sub>R(PD)</sub>	30	V
Operating temperature	Topr	-10 to +70	°C
Storage temperature	Tstg	-40 to +85	°C

Note: Pulse condition: Pulse width = 100 ns, duty = 50%

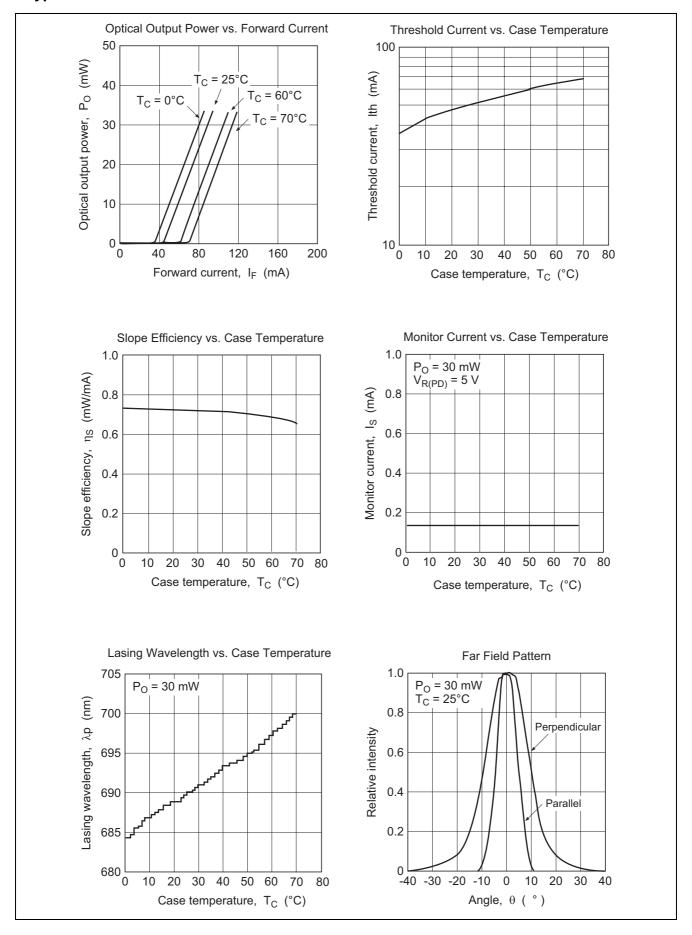
### **Optical and Electrical Characteristics**

 $(T_C = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	lth	30	45	70	mA	_
Operating voltage	V <sub>OP</sub>	2.1	2.5	2.8	V	P <sub>O</sub> = 30 mW
Slope efficiency	ης	0.5	0.7	0.9	mW/mA	18(mW) / (I <sub>(24mW)</sub> – I <sub>(6mW)</sub> )
Beam divergence parallel to the junction	θ//	7	8.5	10.5	o	Po = 30 mW
Beam divergence parpendicular to the junction	θΤ	17	19	23	o	P <sub>O</sub> = 30 mW
Asitgmatism	As	_	6	_	μm	$P_0 = 5 \text{ mW}, \text{ NA} = 0.55$
Lasing wavelength	λр	680	690	695	nm	P <sub>O</sub> = 30 mW
Monitor current	I <sub>S</sub>	0.02	0.1	0.45	mA	$P_0 = 30 \text{ mW}, V_{R(PD)} = 5 \text{ V}$



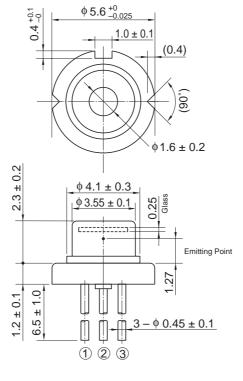
### **Typical Characteristic Curves**

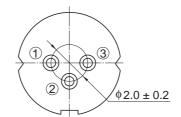


## **Package Dimensions**

As of July, 2002 Unit: mm







OPJ Code	LD/MG
JEDEC	_
JEITA	_
Mass (reference value)	0.3 g



#### **Cautions**

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#### **Sales Offices**



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